Datasheet

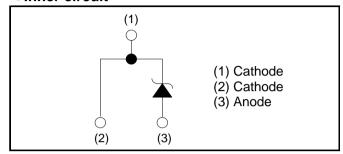
V_R	650V
I _F	10A
$\overline{Q_C}$	24nC

Outline TO-220ACP (1) (2) (3)

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

•Inner circuit



Packaging specifications

	Packaging	Tube
	Reel size (mm)	-
Type	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	C9
	Marking	SCS310AH

Construction

Silicon carbide epitaxial planar type

• Absolute maximum ratings $(T_i = 25^{\circ}C)$

•Absolute maximum ratings (1 = 25°C)				
Parameter		Symbol	Value	Unit
Reverse voltage (re	epetitive peak)	V_{RM}	650	V
Reverse voltage (D	C)	V_R	650	V
Continuous forward	current (T _c = 135°C)	I _F	10	А
Surge non-PW=10ms sinusoidal, T _j =25°C			82	А
repetitive forward	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	69	А
current	PW=10μs square, T _j =25°C		300	А
Repetitive peak forward current		I _{FRM}	45 *1	А
$1 \le PW \le 10 \text{ms}, T_j = 25^{\circ}\text{C}$ $1 \le PW \le 10 \text{ms}, T_j = 150^{\circ}\text{C}$		ſ.2	33	A ² s
		$\int i^2 dt$	23	A ² s
Total power disspation		P_{D}	71 *²	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_i = 25°C)

Parameter	Symbol	Conditions	Values			l lm:t
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =50μA	650	-	-	V
	V _F	I _F =10A,T _j =25°C	-	1.35	1.50	V
Forward voltage		I _F =10A,T _j =150°C	-	1.44	1.71	V
		I _F =10A,T _j =175°C	-	1.50	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	0.03	50	μΑ
		V _R =650V,T _j =150°C	-	2	200	μΑ
		V _R =650V,T _j =175°C	-	6	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	500	-	pF
		V _R =650V,f=1MHz	-	46	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	24	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	15	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	130	-	mJ

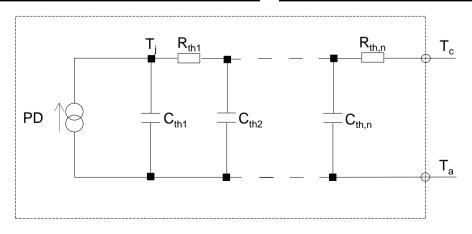
Thermal characteristics

Parameter	Symbol	Conditions -	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	R _{th(j-c)}	-	-	1.5	2.1	K/W

●Typical Transient Thermal Characteristics

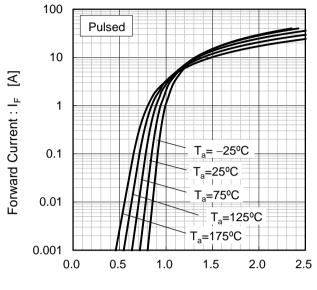
Symbol	Value	Unit
R _{th1}	1.55×10 ⁻²	
R _{th2}	1.46×10 ⁻¹	K/W
R _{th3}	1.32×10 °	

Symbol	Value	Unit
C _{th1}	2.63×10 ⁻⁴	
C _{th2}	1.00×10 ⁻³	Ws/K
C_{th3}	2.13×10 ⁻³	



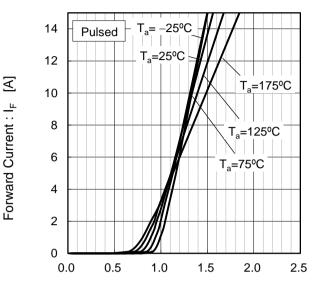
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



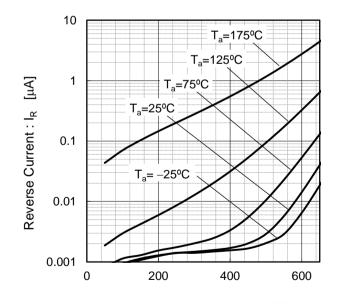
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



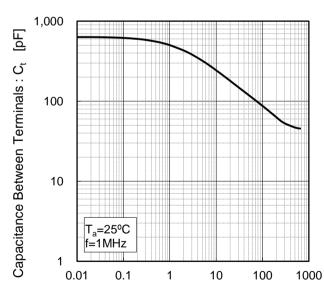
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



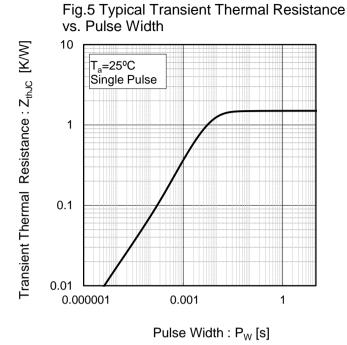
Reverse Voltage : V_R [V]

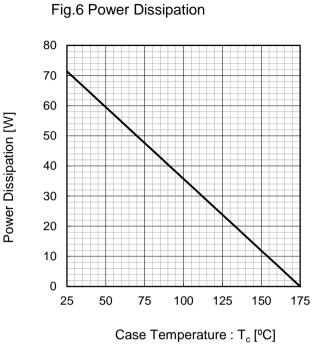
Fig.4 V_R-C_t Characteristics

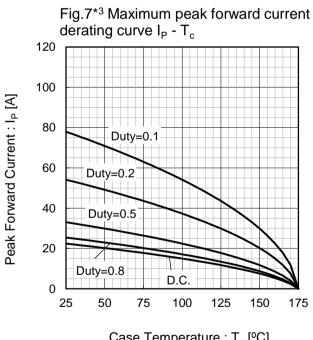


Reverse Voltage : V_R [V]

• Electrical characteristic curves







Case Temperature : T_c [°C]
*3 Based on max Vf, max R_{th(j-c)}
Valid for switching of above 10kHz, excluding D.C. curve.

Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed) Duty=0.1 100 80 Duty=0.2 60 Duty=0.5 40 20 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

Case Temperature : T_c [°C]

*4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid

for switching of above 10kHz,

excluding D.C. curve

Peak Forward Current: Ip [A]

Electrical characteristic curves

vs. Pulse width (Sinusoidal waveform) Surge non-repetitive forward current : I_{FSM} [A] 1000

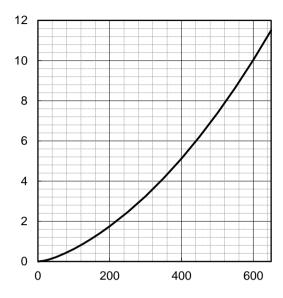
Fig.9 Surge non-repetitive forward current

100 T_a=25°C Single Pulse

Pulse Width: Pw [s]

0.001

Fig.10 Typical capacitance store energy



Capacitance stored energy ։ $\mathsf{E}_\mathsf{C}[\mu J]$

0.01

Reverse Voltage: V_R [V]

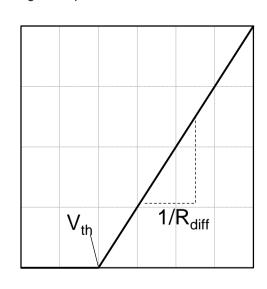
Symplified forward characteristic model

0.0001

0.00001

Forward Current: IF

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th} \left(\ T_{j} \ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff} \left(\ T_{j} \ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a_0	9.66×10 ⁻¹	V
a ₁	-1.1×10 ⁻³	V/°C
b ₀	3.52×10 ⁻²	Ω
b ₁	7.46×10 ⁻⁵	Ω/°C
b ₂	7.68×10 ⁻⁷	Ω /°C ²

 $T_i \text{ in } {}^{\circ}\text{C}$; -55 ${}^{\circ}\text{C}$ < T_i < 175 ${}^{\circ}\text{C}$; I_F < 20 A

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